



RELIABILITY REPORT FOR MAX889TESA+

PLASTIC ENCAPSULATED DEVICES

May 29, 2009

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by
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Conclusion

The MAX889TESA+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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- I. Device Description
 - A. General

The MAX889 inverting charge pump delivers a regulated negative output voltage at loads of up to 200mA. The device operates with inputs from 2.7V to 5.5V to produce an adjustable, regulated output from -2.5V to -VIN. The MAX889 is available with an operating frequency of 2MHz (T version), 1MHz (S version), or 0.5MHz (R version). The higher switching frequency devices allow the use of smaller capacitors for space-limited applications. The lower frequency devices have lower quiescent current. The MAX889 also features a 0.1µA logic-controlled shutdown mode and is available in an 8-pin SO package. An evaluation kit, MAX889SEVKIT, is available.



II. Manufacturing Information

High-Frequency, Regulated, 200mA, Inverting Charge Pump

S12

Oregon

July 21, 2000

ATP Philippines, UTL Thailand

A. Description/runction.	Α.	Description/Function:
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- B. Process:
- C. Number of Device Transistors:
- D. Fabrication Location:
- E. Assembly Location:
- F. Date of Initial Production:

III. Packaging Information

A. Package Type:	8-pin SOIC (N)
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive Epoxy
E. Bondwire:	Gold (1.3 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-1101-0159
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	170°C/W
K. Single Layer Theta Jc:	40°C/W
L. Multi Layer Theta Ja:	128.4°C/W
M. Multi Layer Theta Jc:	36°C/W

IV. Die Information

A. Dimensions:	85 X 121 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide
C. Interconnect:	Aluminum/0.5% Cu
D. Backside Metallization:	None
E. Minimum Metal Width:	1.2 microns (as drawn)
F. Minimum Metal Spacing:	1.2 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts:	Ken Wendel (Director, Reliability Engineering) Bryan Preeshl (Managing Director of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet.0.1% For all Visual Defects.
C. Observed Outgoing Defect Rate:	< 50 ppm
D. Sampling Plan:	Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{MTTF} = \underbrace{\frac{1.83}{192 \times 4340 \times 240 \times 2}}_{(where \ 4340 \ = \ Temperature \ Acceleration \ factor \ assuming \ an \ activation \ energy \ of \ 0.8eV)}$ $\lambda = 4.5 \times 10^{-9}$

𝔅 = 4.5 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly 1000 hour life test monitors on its processes. This data is published in the Product Reliability Report found at http://www.maxim-ic.com/. Current monitor data for the S12 Process results in a FIT Rate of 0.09 @ 25C and 1.48 @ 55C, data limited (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard $85^{\circ}C/85\%$ RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The PX57-2 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500 V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250 mA.



Table 1 Reliability Evaluation Test Results

MAX889TESA+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test	(Note 1)				
	Ta = 135°C	DC Parameters	240	0	
	Biased	& functionality			
	Time = 192 hrs.				
Moisture Testing	(Note 2)				
85/85	Ta = 85°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 1000hrs.				
Mechanical Stres	ss (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
-	Method 1010				

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data